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APPLICATION	NO. F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/661,543	1	09/15/2003	Shingo Saigo	8040-1050	9065		
466	7590	03/16/2006		EXAM	EXAMINER		
YOUNG	G & THOM	PSON	KIM, RIC	KIM, RICHARD H			
745 SOU 2ND FL	JTH 23RD ST	reet	ART UNIT	PAPER NUMBER			
	GTON, VA	22202	2871	2871			
			DATE MAILED: 03/16/2006				

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No		Applicant(s)					
ı		10/661,543	,	SAIGO ET AL.					
	Office Action Summary	Examiner		Art Unit					
		Richard H. Kim		2871					
Period fo	The MAILING DATE of this communication apport Reply	pears on the cove	r sheet with the co	orrespondence ac	idress				
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPL' CHEVER IS LONGER, FROM THE MAILING Donsions of time may be available under the provisions of 37 CFR 1.1 SIX (6) MONTHS from the mailing date of this communication. It is period for reply is specified above, the maximum statutory period to reply within the set or extended period for reply will, by statute reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS CO 36(a). In no event, how will apply and will expire c, cause the application	OMMUNICATION vever, may a reply be time SIX (6) MONTHS from to to become ABANDONED	ely filed the mailing date of this coorsists (35 U.S.C. § 133).					
Status									
1)	Responsive to communication(s) filed on 28 D	ecember 2005							
2a)⊠	This action is FINAL . 2b) This action is non-final.								
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the ments is								
ت(۵	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.								
Dispositi	ion of Claims								
		ion							
•	Claim(s) <u>4 and 5</u> is/are pending in the application.								
	4a) Of the above claim(s) is/are withdrawn from consideration.								
·	☐ Claim(s) 4 and 5 is/are rejected.								
7)[
8)[_]	Claim(s) are subject to restriction and/o	or election require	ement.		•				
Applicati	ion Papers								
9)	The specification is objected to by the Examine	er.							
10)	The drawing(s) filed on is/are: a) acc	epted or b) ob	jected to by the E	xaminer.					
	Applicant may not request that any objection to the	drawing(s) be held	d in abeyance. See	37 CFR 1.85(a).					
	Replacement drawing sheet(s) including the correct	tion is required if th	ne drawing(s) is obje	ected to. See 37 C	FR 1.121(d).				
11)	The oath or declaration is objected to by the Ex	caminer. Note the	e attached Office	Action or form P1	ГО-152.				
Priority ι	ınder 35 U.S.C. § 119			•					
12\□	Acknowledgment is made of a claim for foreign	nriority under 3	5115C & 119(a).	(d) or (f)					
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of:									
u).		e have been rec	oivod						
	2. Certified copies of the priority documents have been received in Application No								
	3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).								
* 0	· ·	•							
	See the attached detailed Office action for a list	or the certified C	opies not received	J.					
	·								
Attachmen	t(s)								
	e of References Cited (PTO-892)	4) 🗌	Interview Summary (
	e of Draftsperson's Patent Drawing Review (PTO-948)		Paper No(s)/Mail Dat Notice of Informal Pa		D-152\				
	nation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) r No(s)/Mail Date	6)		nent Application (PTC					

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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 4-5 are rejected under 35 U.S.C. 103(a) as being unpatentable over Moon et al. (US 2002/0093614 A1) in view of Choo et al. (US 6,642,979 B2).

Referring to claims 4 and 5, Moon et al. discloses a method comprising the steps of forming a first inorganic insulation film on at least source and drain electrodes of the thin film transistor (Fig. 7C, ref. 130), forming first contact holes (145) in the first inorganic insulating film for connecting the common wiring (135) and the common electrode (117) to each other (Fig. 7C, ref. 135, 117), and second contact holes (141) for connecting the thin film transistors (T) and the pixel electrode (131), forming the common electrode connected to the common line via the first contact hole, and forming pixel electrodes connected to the thin film transistor via the second contact hole. However, the reference does not disclose forming a second inorganic insulating film on the first inorganic insulating film, forming third contact holes so as to be superposed on the second contact holes, forming a conductive film on the second inorganic insulating film, and using at least dry etching, wherein the third contact holes are formed inside the first contact holes while the fourth contact holes are formed inside the second contact holes.

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Choo et al. (US 6,642,979 B2) discloses a second inorganic insulating film on a first inorganic insulating film, forming fourth contact holes so as to be superposed on the second contact holes (131), forming a conductive film on the second inorganic insulating film (117), wherein the fourth contact holes are formed inside the second contact holes (131).

It would have been obvious to one having ordinary skill in the art at the time the invention was made to employ methods of disclose forming a second inorganic insulating film on the first inorganic insulating film, forming third contact holes so as to be superposed on the first contact holes, and fourth contact holes so as to be superposed on the second contact holes, forming a conductive film on the second inorganic insulating film, wherein the third contact holes are formed inside the first contact holes while the fourth contact holes are formed inside the second contact holes since one would be motivated to provide added insulation to thereby prevent short-circuiting between two conductive elements. Furthermore, even though Choo et al. does not disclose the third contact holes, adding another insulating layer in order to prevent short-circuiting between two conductive elements as shown in Choo et al. is a well known technique. Therefore, employing the teachings of Choo et al. to Moon et al. in order to provide added insulation to thereby form a third contact hole would have been obvious. Furthermore, dry etching is a well known process in the art to precisely fabricate contact holes.

Response to Arguments

3. Applicant's arguments filed 12/28/05 have been fully considered but they are not persuasive.

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- 4. In response to Applicant's argument that Moon et al. does not disclose a first inorganic insulating film on at least source and drain electrodes, Examiner submits that inorganic insulating film (130) is above at least the source and drain electrodes.
- 5. Furthermore, it is clear that the second contact hole connects the pixel electrode with the thin film transistor as illustrated in Figure 6E, reference numeral 137 and 133.
- 6. In response to Applicant's argument that Choo et al. discloses only one hole through two layer, Examiner submits that the invention of Choo et al. can also be interpreted as having one hole in each layer and superposed on one another. Therefore, Choo et al. reads on the claimed limitation.

Conclusion

7. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

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however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Richard H. Kim whose telephone number is (571)272-2294. The examiner can normally be reached on 9:00-6:30 M-F.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert H. Kim can be reached on (571)272-2293. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Richard H Kim Examiner Art Unit 2871

RHK

ANDREW SCHECHTER
PRIMARY EXAMINER